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Vishay Semiconductors

Thyristor High Voltage, Phase Control SCR, 25 A



PRIMARY CHARACTERISTICS							
I _{T(AV)} 16 A							
V _{DRM} /V _{RRM}	800 V, 1200 V						
V _{TM}	1.25 V						
I _{GT}	45 mA						
T _J	-40 °C to 125 °C						
Package	TO-220AB 3L						
Circuit configuration	Single SCR						

FEATURES

- Designed and qualified according to JEDEC®-JESD 47
- 125 °C max. operating junction temperature
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding, and battery charge.

DESCRIPTION

The VS-25TTS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS									
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	18	22	А						

MAJOR RATINGS AND CHARACTERISTICS										
PARAMETER	TEST CONDITIONS	VALUES	UNITS							
I _{T(AV)}	Sinusoidal waveform	16	A							
I _{RMS}		25	A							
V _{RRM} /V _{DRM}		800, 1200	V							
I _{TSM}		320	Α							
V _T	16 A, T _J = 25 °C	1.25	V							
dV/dt		500	V/µs							
dl/dt		150	A/μs							
TJ		-40 to +125	°C							

VOLTAGE RATINGS										
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA							
VS-25TTS08-M3	800	800	10							
VS-25TTS12-M3	1200	1200	10							

VS-25TTS08-M3, VS-25TTS12-M3

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ABSOLUTE MAXIMUM RATINGS								
DADAMETED	SYMBOL	TEST 001	NDITIONS	VAL	UNITS			
PARAMETER	SYMBOL TEST CONDITIONS			TYP.	MAX.	ONITS		
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° conduc	tion half sine wave	16				
Maximum RMS on-state current	I _{RMS}			2	25	Α		
Maximum peak, one-cycle,	1	10 ms sine pulse, rated \	/ _{RRM} applied	2	70	_ A		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no volt	age reapplied	3	20			
Marriage up 12t for fraing	I ² t	10 ms sine pulse, rated \	/ _{RRM} applied	365		A ² s		
Maximum I ² t for fusing	I-I	10 ms sine pulse, no volt	515		A-s			
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no volta	5152		A²√s			
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.25		٧		
On-state slope resistance	r _t	T _J = 125 °C		12.0		mΩ		
Threshold voltage	V _{T(TO)}	1J = 125 C		1.0		V		
Maximum reverse and direct leakage current	1/1	T _J = 25 °C	V _B = Rated V _{BBM} /V _{DBM}	0	.5			
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C	VR = hated VRRM/VDRM	10				
Holding current	l _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		ı	150	mA		
Maximum latching current	lμ	Anode supply = 6 V, resi	200					
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear to } 80$	T _J = T _J max., linear to 80 °C, V _{DRM} = R _g - k = Open					
Maximum rate of rise of turned-on current	dl/dt			1:	A/µs			

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P _{GM}		8.0	W	
Maximum average gate power	P _{G(AV)}		2.0	VV	
Maximum peak positive gate current	+ I _{GM}		1.5	Α	
Maximum peak negative gate voltage	- V _{GM}		10	V	
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	60		
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	45	mA	
		Anode supply = 6 V, resistive load, T _J = 125 °C	20		
		Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5		
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	,,	
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V	
Maximum DC gate voltage not to trigger	V_{GD}	T 105 °C V Detect value	0.25		
Maximum DC gate current not to trigger	I_{GD}	T _J = 125 °C, V _{DRM} = Rated value	2.0	mA	

SWITCHING								
PARAMETER SYMBOL TEST CONDITIONS VALUES								
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9					
Typical reverse recovery time	t _{rr}	T _J = 125 °C	4	μs				
Typical turn-off time	t _q	1J = 125	110					

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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +125	°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.1				
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque -	minimum			6 (5)	kgf · cm			
wounting torque –	maximum			12 (10)	(lbf · in)			
Maddonator			Consectula TO 220AP 21	25TTS08				
Marking device		Case style TO-220AB 3L		25TTS12				

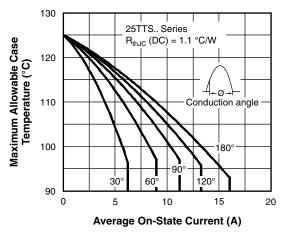


Fig. 1 - Current Rating Characteristics

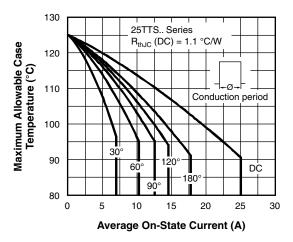


Fig. 2 - Current Rating Characteristics

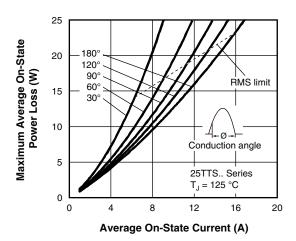


Fig. 3 - On-State Power Loss Characteristics

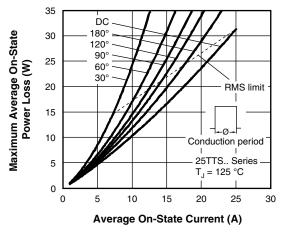


Fig. 4 - On-State Power Loss Characteristics

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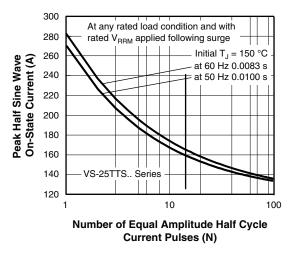


Fig. 5 - Maximum Non-Repetitive Surge Current

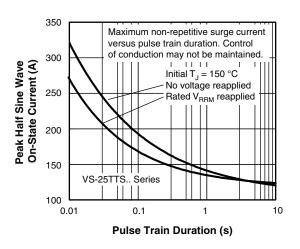


Fig. 6 - Maximum Non-Repetitive Surge Current

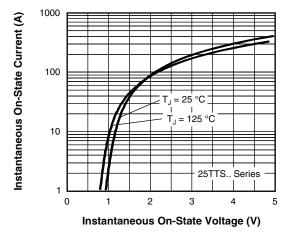


Fig. 7 - On-State Voltage Drop Characteristics

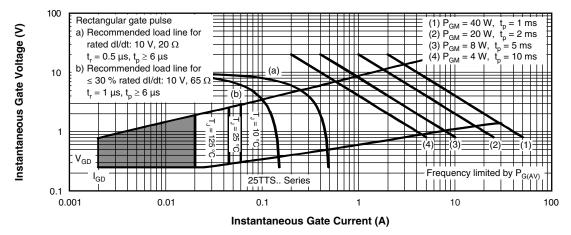


Fig. 8 - Gate Characteristics

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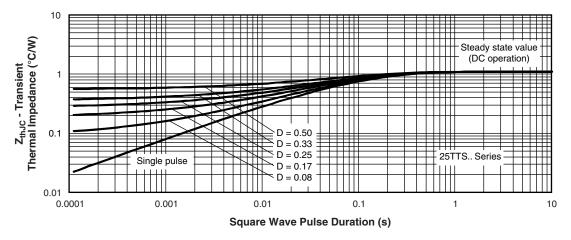
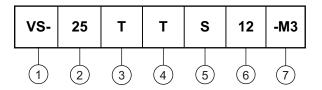


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Current rating (25 = 25 A)

3 - Circuit configuration:

T = single thyristor

4 - Package:

T = TO-220AB

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage rating -- 08 = 800 V 12 = 1200 V

7 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-25TTS08-M3	50	Antistatic plastic tubes					
VS-25TTS12-M3	50	Antistatic plastic tubes					

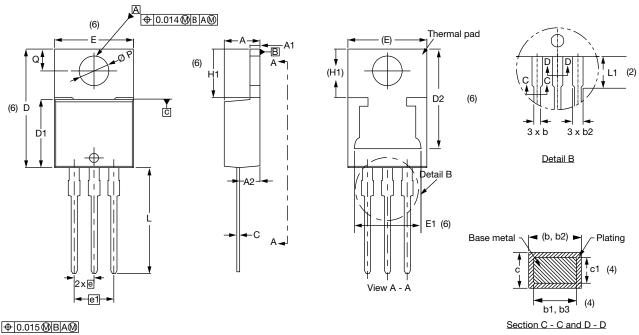
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96154</u>						
Part marking information	www.vishay.com/doc?95028					

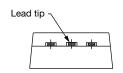


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TO-220AB 3L

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIMETERS		INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355								

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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